SE6567X & SE6568X

Master/Slave





Description

SE6567X & SE6568X is a special purpose OEM master/slave diode driver to supply high power fiber lasers pumping stages for laser drone defense systems.

For mobile application it provides a variable battery supplied input ranging from 52 o 60 VDC.

Its boost topology supplies diodes with compliance voltage to 95 VDC.

All circuitry is encased within a milled aluminium IP67 sealed housing. Water cooling is integrated into the monolithic chassis structure.

Integrated high current contactors disconnect the battery input from the driver electronics on demand.

The main current input is split into the internal master supply with 3 diode driver outputs and a feed-through slave supply to the slave chassis to provide additional 6 diode driver outputs.

Each driver can individually be programmed.

For other driver configurations or different applications please contact our product management.

Features

- Water cooled IP67 chassis
- Output 9x up to 28 A/95 V
- Boost output U_{out} up to 95 V from 52 ..60 VDC battery input
- Battery supply input max. 475 A
- Fully isolated digital interfaces
- typ. 150 µs rise/fall time
- Safety up to Performance Level e (EN 13849-1)

Specifications

Output max. 24 kW, 3 + 6 chn. each 0 .. 28 A / 5 .. 95 V $^{1)}$

Rise time ca. 100 .. 200 µs 2) Current ripple typ. 0.2% (of full scale) Digital control RS485 and USB

Driver protective features/ error output Monitor starting sequence, soft start, transient protection, OVP, over temperature protection, user current limit, shut down reaction time <1 μs

output discharge circuit

Thermal monitoring: M/S baseplate, Aux PSU, high-

current input connectors, 9x driver PCB Safety relay monitored redundant high current

contactors, emergency stop

Digital interface completely isolated towards power

stage.

Efficiency typ. 96 .. 98.5 %

Input tvp. 52 .. 60 VDC. max. 475 A min. +5 °C .. +50 °C Environment

Cooling

max. power dissipation ca. 800 W Heat loss

DC connectors in/out MIL-DTL-38999

Size Mainframe master 3U, depth 515 mm Mainframe slave 2U, depth 457 mm

Weight: ca. 28 + 23 kg

¹⁾ Higher output to 125 VDC in boost operation available. Up to 400 VDC diode driver output on request for buck mode operation.

Rise/fall time performance down to 50 µs for CW drivers available. Faster CW to QCW performance on request